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Remarks

The applicants have attended to the formal matters. In particular in the proposed drawing correction the drawings have been amended to more clearly show the legends in Figures 5a, 5b, 6a, 6b, 7a, 8a, 9a, and 10a. The title has been amended to that proposed by the Examiner.

Errors in the specification have been corrected. In particular the drawing references from Figure 4 onwards were one number too high in the body of the specification. This was an erroneous carry-over from a previous draft of the application. The description in the Brief Description of the Drawings was correct. Other minor errors have been corrected.

The claims have been defined to more clearly define the invention, and in particular the optimization steps required to produce high quality films (see, for example, the passage commercing at line 22, page 29, and going on to page 30, which explains have the system can be considered a five-dimensional space with only the fourth independent variable being varied and the observed fift in characteristics are observed to optimize the films.

The Examiner has recognized that the application relates to the production of optical quality ailicia filians for us in avergation and like devices. The presence of absorption peaks in the wavebands of interest negatively impact on the optical properties of the device. As explained in the specification, these absorption peaks typically arise as a result of contaminants formed during the PECVD deposition process. The object of the invention is to obtain a silica film wherein as far as possible these contaminants are sliminated. In the prior at one method was to subject the films to a high temperature meanal as a temperature of about 1590°C. This snancel creates is conviproblems, and the invention permits high quality films to be produced when subjected to lower temperature poor treatments, perfected by 800°C.

The extensive studies carried out by the applicants and described in the heighty specification above that if the gas flow rates are fixed, particularly good results are obtained if the total pressure is maintained between 2.0 and 2.6 Torr (see, for example, Figure 6b). The problem is that there are so many process variables that potentially one can play with in order to control the reaction, the number of possible combinations is very high. One skilled in the art could make an infinite number of ediputments with no ostainty of success. Some might give improved results. Some might give worse results. The person skilled in the art would estontially have to make rendom trials over a very large number of consible numberations.

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What the applicants show is that the significant parameter affecting the quality of the titus is the total gas persuare and that the flow mass have relatively lintle impact. Thus, by fixing the flow rare and varying the total gas pressure between within the desired range it is possible to identify the total gas pressure that results in optimum quality films. This optimization step only requires a manageable number of steps and as explained in the specification will permit the production of high quality films that do not requires an anneal at a temperature above 1200°C, and which in practice can produce good quality films with the aid of a post-deposition anneal at a temperature as low as 800°C.

The prior ant does not show the sequence of steps now recited in claims 1 and 21. Shloye has nothing to do with the deposition of optical quality films. The poor deposition heat treatment suggested in this pixet is purely for the purposes of observing the cracking resistance of the deposited films. While this patent may have had accidental relevance to the original claims, it is not believed relevant to the amended claims. It does not disclose the optimization steps now claims.

Neither Ojha nor Bouffland discloses the optimization method claimed wherein the gas Blow rates are predetermined and then the optimization test persons within the specified range is determined in the manner claimed. The Essentiner cites Law as disclosing optimization (see Boot of page 11 of the office action). However, Law (see col. 3, lines 2 – 5), just makes the general statement but the process variables can be optimized. This may be a trainer, but in practice the question is how to achieve optimization in a meaningful and orderly manner. The problem is that, as pointed out earlier, in a EECV process there are many process variables that can be changed, and a person skill of in the art would encounter an endless variety of permutations. The invention puts some order into this jumble of possible variations by stabilishing that by fixing the flow rates and adjusting the toost deposition pressure within the specified range is is possible to produce silica films of high agical quality because the absorption characteristics of the films are heavily dependent on the volal pressure. This has to statular, the prior art.

It is clear that the prior art does not in reality teach the present invention, which in practice represents a very significant step forward in the art. In the absence of the teachings of the specification, one skilled in the art would not know that improved optical quality films that did not need a very high temperature anneal could be produced by carrying out the specific steps USSN 09/833,711 Art Unit: 1762

claimed. The citterion for orbivolances is not whether one skilled in the art could practice the invention, but whether in practice one would do so, whether one sought be motivated to do so in the absence of the applicant's teachings. It is not permissible to use the applicant's own teachings as blueprint for reconstructing the invention from the prior art. in the applicant's respectful assumes of the respect to the proper state of the applicant's own teachings as blueprint for reconstructing the invention from the prior art. in the applicant's respectful submission there is no reason to suggest that one skilled in the art would the motivate to carry out the specific steps now set forth in the claims, an in particular claims 1 and 21 with the exceptation of obtaining any useful results.

With regard to double-passenting objections it is noted that the present application has an earlier filling date than the cited pending englisacions. Consideration will be given to Hilling a terminal disclaimer during the prosecution of the later-filed applications should that be deemed necessary. It is respectfully authoritied that it is not necessary to file a terminal disclaimer in respect of the present applications since it prior dates the certifier applications and will inherently expire before them, and furthermore that the claims as amended are patentably distinct from the cited expolications.

Reconsideration and allowance are respectfully requested.

Respectfully submitted,

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